

SI9926BDY-T1-E3

SI9926BDY-T1-E3 Information

with persener.com	SI9926BDY-T1-E3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CH 20V 6.2A 8-SOIC 8-SOIC (0.154", 3.90mm Width) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI9926BDY-T1-E3 Specifications

Manufacturer Part Number	SI9926BDY-T1-E3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SOIC (0.154", 3.90mm Width)
Series	TrenchFET?
FET Type	2 N-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	6.2A
Rds On (Max) @ Id, Vgs	20 mOhm @ 8.2A, 4.5V
Vgs(th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	1.14W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SOIC (0.154", 3.90mm Width)
Supplier Device Package	8-SO
	Report errors?

SI9926BDY-T1-E3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

SI9926BDY-T1-E3 Payment Methods



SI9926BDY-T1-E3 Shipping Methods



If you have any question about SI9926BDY-T1-E3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com